## NSN 5962-00-433-6281

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View Online at https://aerobasegroup.com/nsn/5962-00-433-6281
Body Length:
Between 1.200 inches and 1.290 inches
Body Width:
Between 0.515 inches and 0.580 inches
Body Height:
Between 0.050 inches and 0.230 inches
Maximum Power Dissipation Rating:
650.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and negative outputs and positive outputs and bipolar and w/decoded output and w/enable and w/storage
and programmable and programmed
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
11 input
Case Outline Source And Designator:
-0-015-aa joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
0.3 volts power source
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
92755-12793 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a

Yes - demil/mli

**Unit Of Measure:** 

Demilitarization:

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